NSN 5961-00-360-1986

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-360-1986 **Inclosure Material:** Glass and metal **Overall Length:** 0.782 inches **Overall Diameter:** 0.505 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 10.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 0.5 watts average gate power-forward **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Terminal Type And Quantity:** 1 case and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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